

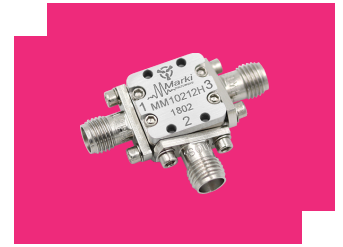
MM1-0212HS

GaAs MMIC Double Balanced Mixer

DEVICE OVERVIEW

General Description

MM1-0212H is a GaAs MMIC double balanced mixer that is optimized for low frequency applications. MM1-0212H is a low frequency S band mixer that works well as both an up and down converter to through X band. This mixer offers low conversion loss and high LO to RF isolations at moderate LO powers. The sister MM1-0212S is recommended for applications which demand higher linearity. The MM1-0212L is recommend for low power applications. The MM1-0212H is available as both wire bondable die and as connectorized modules.



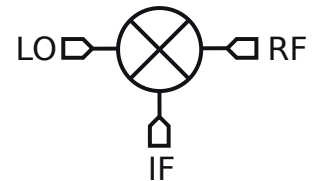
Features

- High LO to RF isolation
- Low cost X band mixer

Applications

- Test and Measurement Equipment

Functional Block Diagram



Part Ordering Options

Part Number	Description	Package	Connectors	Green Status	Product Lifecycle	Export Classification
MM1-0212HS	GaAs MMIC Double Balanced Mixer	S	<u>Standard</u>	REACH RoHS	Released	EAR99

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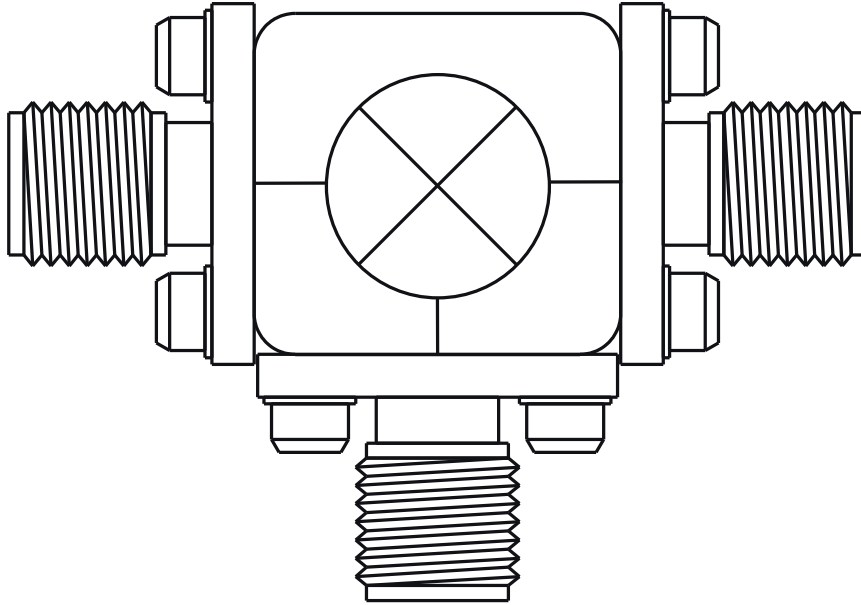
Revision History

Revision Code	Revision Date	Comment
-	2018-01-01	Datasheet Initial Release
A	2019-01-01	Added max power/current spec, ESD rating

Port Configuration and Functions

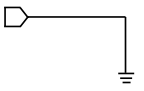
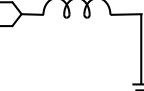
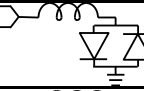
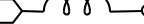
Port Diagram

The MM1-0212H has the input and output ports given in Port Functions. The MM1-0212H can be used in either an up or down conversion. For configuration A, input the LO into port 1, use port 3 for the RF, and port 2 for the IF. For configuration B, input the LO into port 3, use port 1 for the RF, and port 2 for the IF

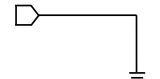
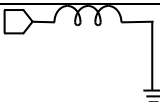




Port Functions

Configuration A

Port	Function	Connector Type	Description	Equivalent Circuit for Package
GND	Ground	-	CH package ground path is provided through the substrate and ground bond pads.	
Port 1	LO	SMAF	Port 1 is DC short for the CH and S packages.	
Port 2	IF	SMAF	Port 2 is diode connected for the CH and S package.	
Port 3	RF	SMAF	Port 3 is DC open for the CH and S packages.	

Configuration B

Port	Function	Connector Type	Description	Equivalent Circuit for Package
GND	Ground	-	S package ground provided through metal housing and outer coax conductor.	
Port 1	RF	SMAF	Port 1 is DC short for the CH and S packages.	
Port 2	IF	SMAF	Port 2 is diode connected for the CH and S package.	
Port 3	LO	SMAF	Port 3 is DC open for the CH and S packages.	

Specifications

Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime.

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
Port 1 DC Current	30	mA
Port 2 DC Current	30	mA
Power Handling, at any Port	30	dBm

Package Information

Parameter	Details	Rating
ESD	250 to < 500 Volts	HBM Class 1A
Weight	Package name: S	10g
Dimensions	-	14.22 x 13.21 mm

Recommended Operating Conditions

The Recommended Operating Conditions indicate the limits, inside which the device should be operated, to guarantee the performance given in Electrical Specifications. Operating outside these limits may not necessarily cause damage to the device, but the performance may degrade outside the limits of the electrical specifications. For limits, above which damage may occur, see Absolute Maximum Ratings.

Parameter	Min	Nominal	Max	Unit
LO Input Power	13	-	17	dBm
Ambient Temperature	-55	25	100	°C

Sequencing Requirements

There is no requirement to apply power to the ports in a specific order. However, it is recommended to provide a 50Ω termination to each port before applying power. This is a passive diode mixer that requires no DC bias.

Electrical Specifications

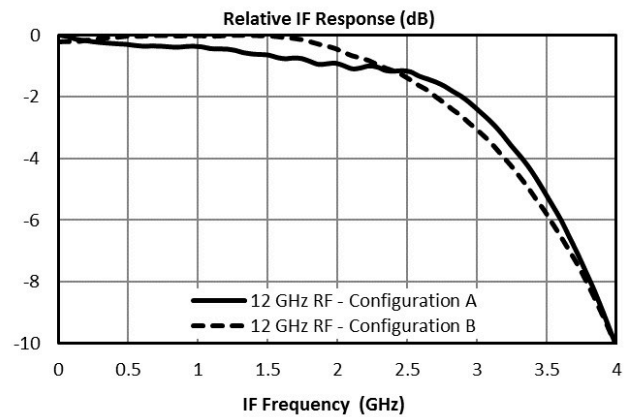
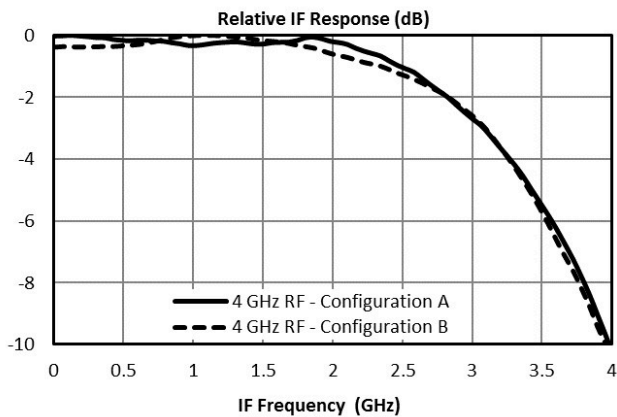
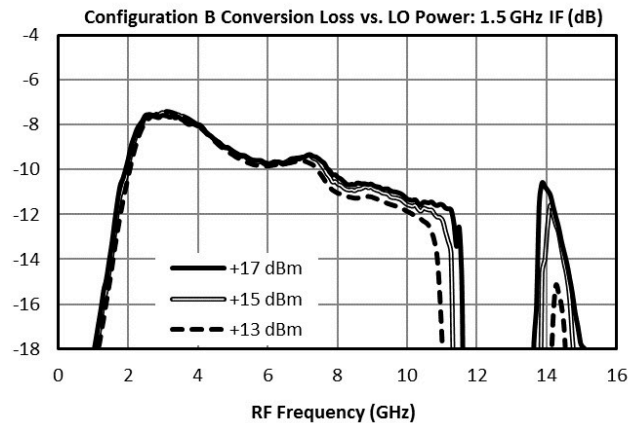
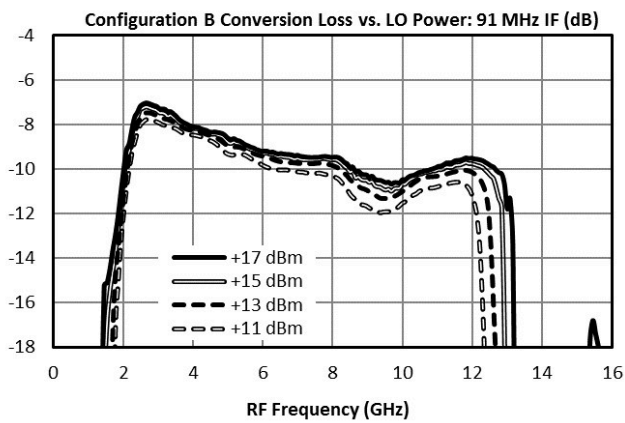
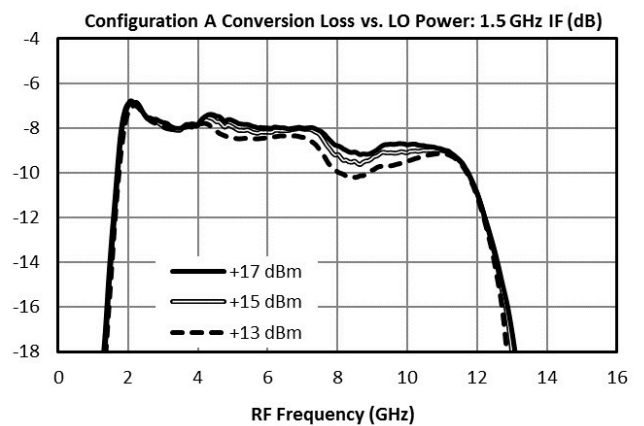
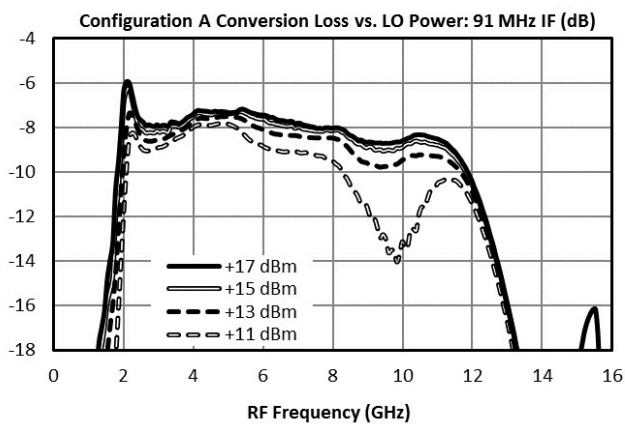
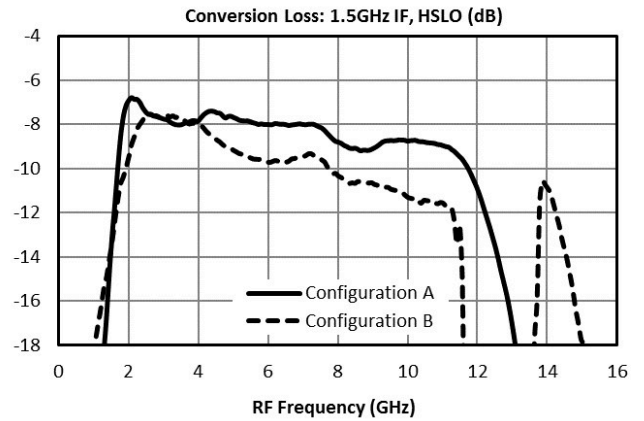
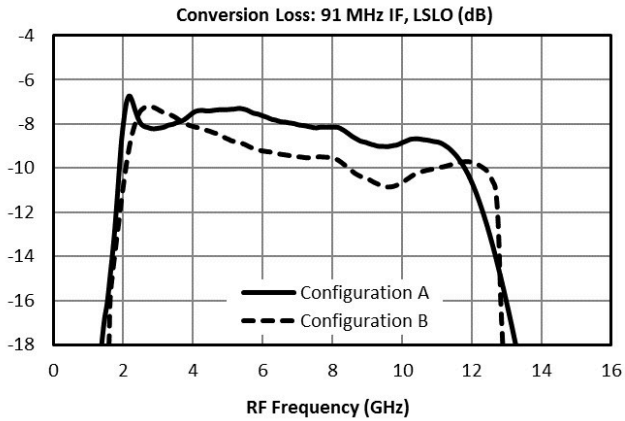
The electrical specifications apply at TA=+25°C in a 50Ω system. Typical data shown is for the connectorized S package mixer used in the forward direction with a +15 dBm sine wave input. Min and Max limits apply only to our connectorized units and are guaranteed at TA=+25°C. All bare die are 100% DC tested and visually inspected.

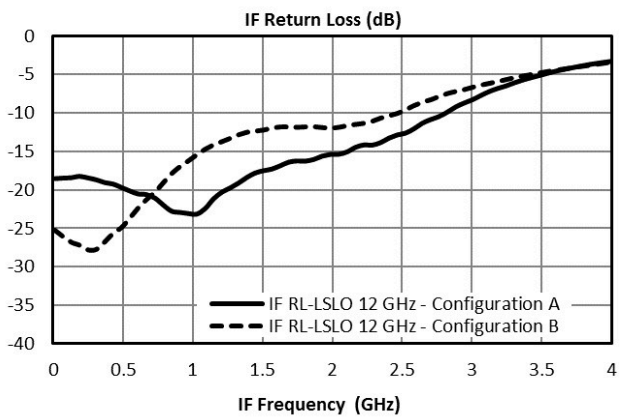
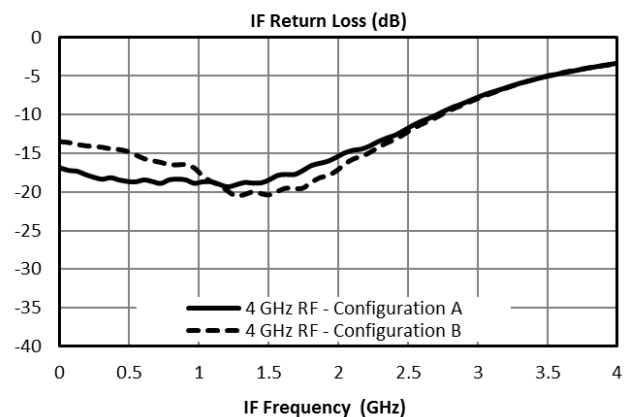
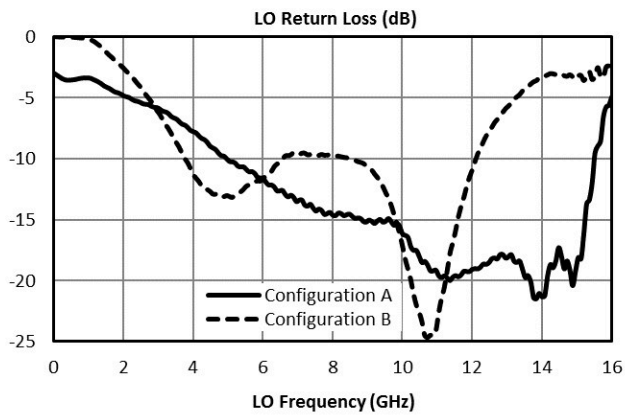
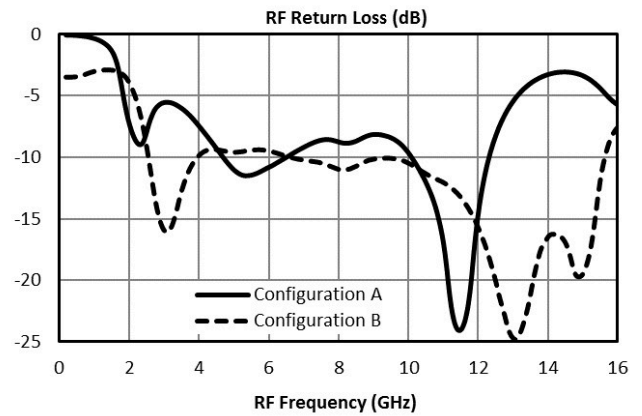
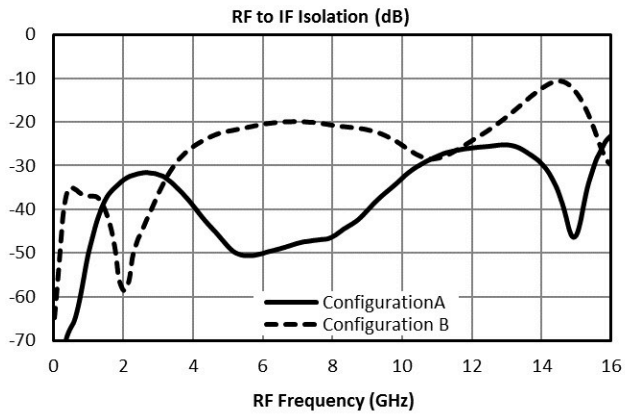
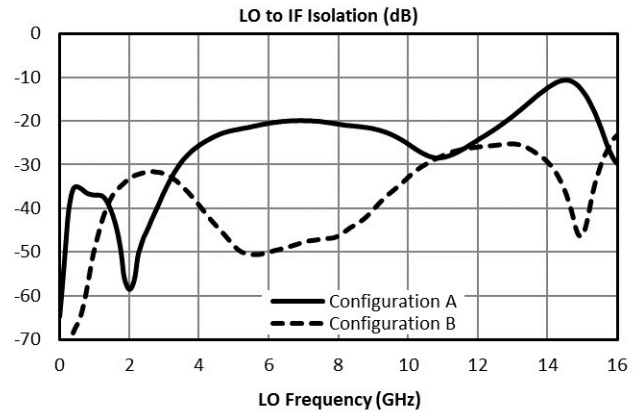
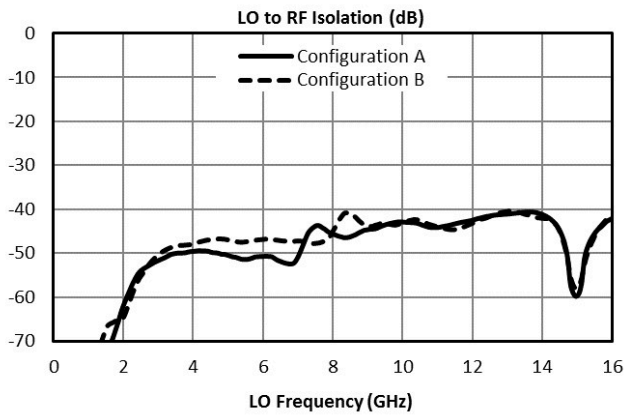
Parameter	Port Configuration	Test Conditions	Min	Typ	Max	Unit
Conversion Loss ¹	A	RF/LO = 2 - 12 GHz I = 0.2 - 3 GHz	-	9.5	-	dB
Conversion Loss ²	A	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz	-	8.5	11.5	dB
Input 1 dB Gain Compression Point (P1dB)	A	-	-	12	-	dBm
Input IP3	A	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz	-	23	-	dBm
Conversion Loss ³	B	RF/LO = 2 - 12 GHz I = 0.2 - 3 GHz	-	11	-	dB
Conversion Loss ⁴	B	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz	-	10	13	dB
Input 1 dB Gain Compression Point (P1dB)	B	-	-	14	-	dBm
Input IP3	B	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz	-	20	-	dBm
IF Frequency Range	-	-	0	-	3	GHz
Isolation, LO to IF	-	IF/LO = 2 - 12 GHz	-	49	-	dB
Isolation, LO to RF	-	RF/LO = 2 - 12 GHz	-	47	-	dB
Isolation, RF to IF	-	RF/IF = 2 - 12 GHz	-	39	-	dB
LO Frequency Range	-	-	2	-	12	GHz
Noise Figure ⁵	-	RF/LO = 2 - 12 GHz I = DC - 0.2 GHz	-	9	-	dB
RF Frequency Range	-	-	2	-	12	GHz

[1][2][3][4] Measured as a down converter to a fixed 91MHz IF.

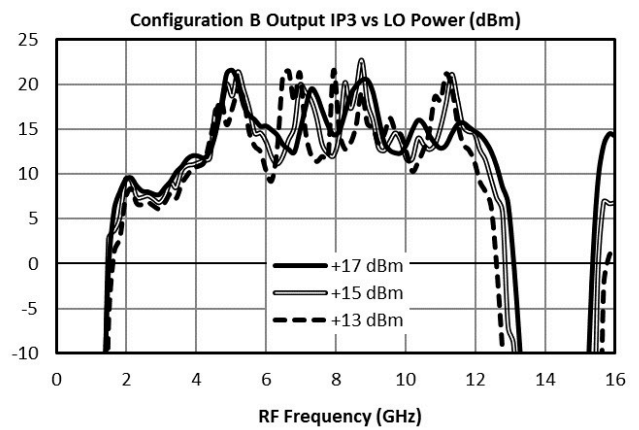
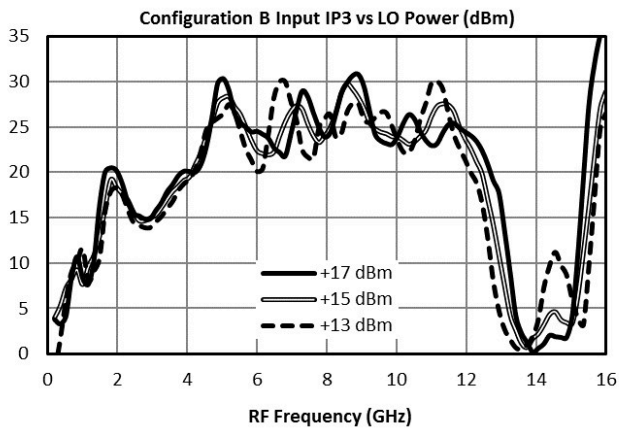
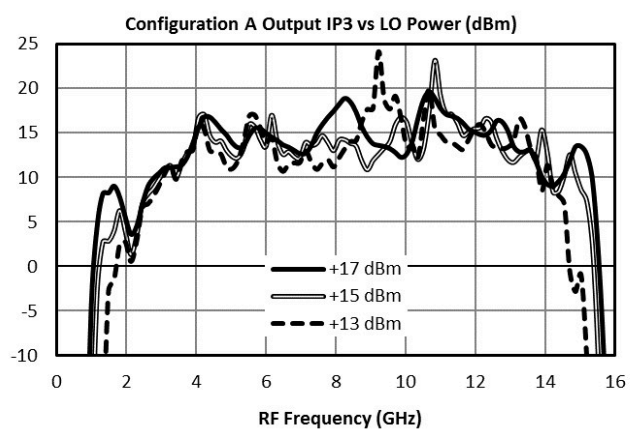
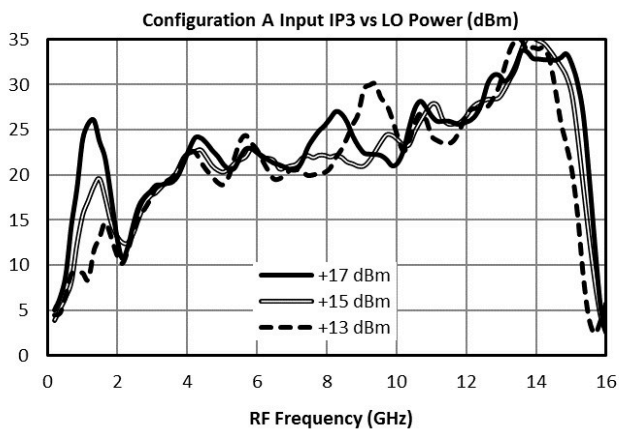
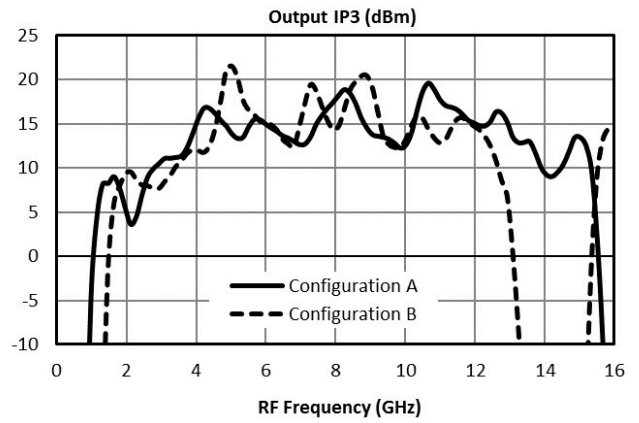
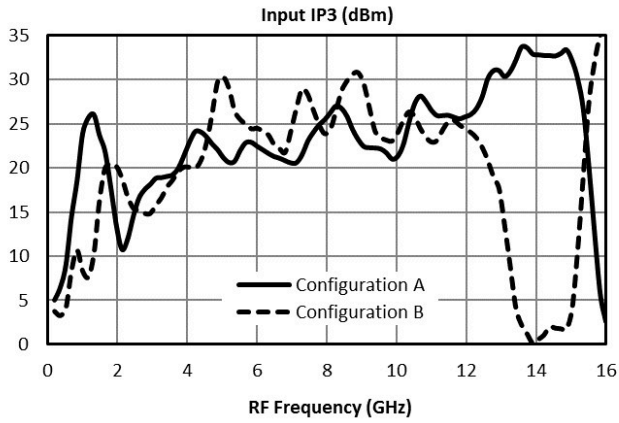
[5] Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.

Typical Performance Plots

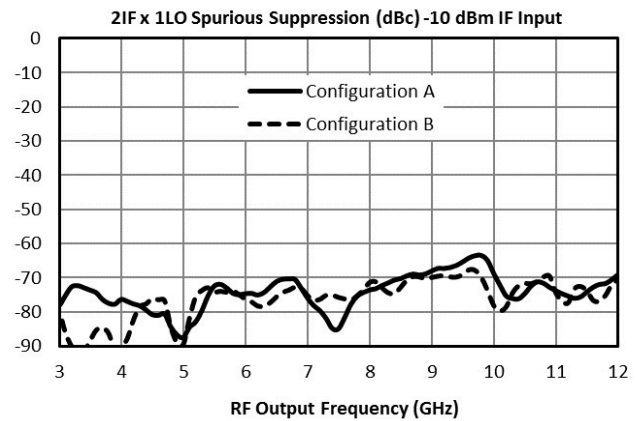
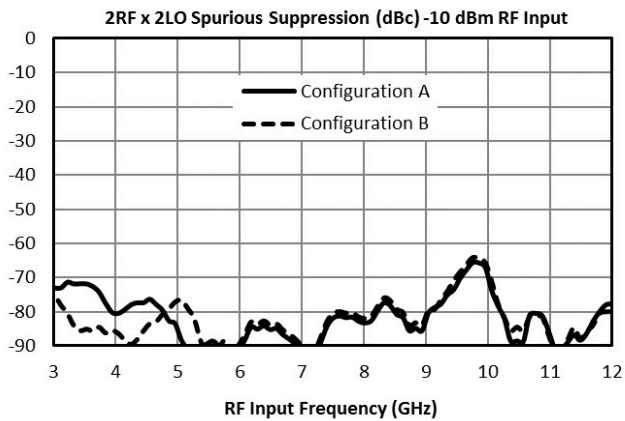
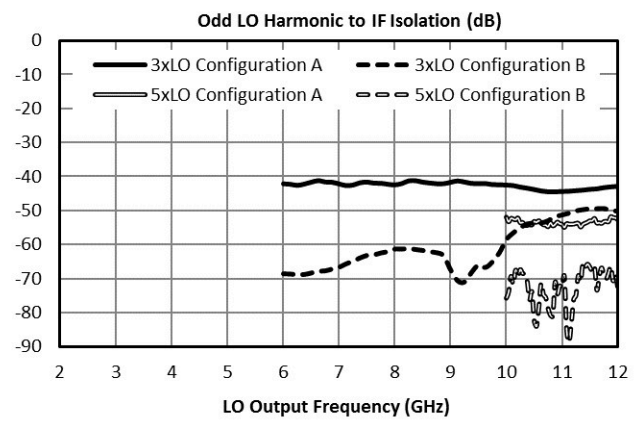
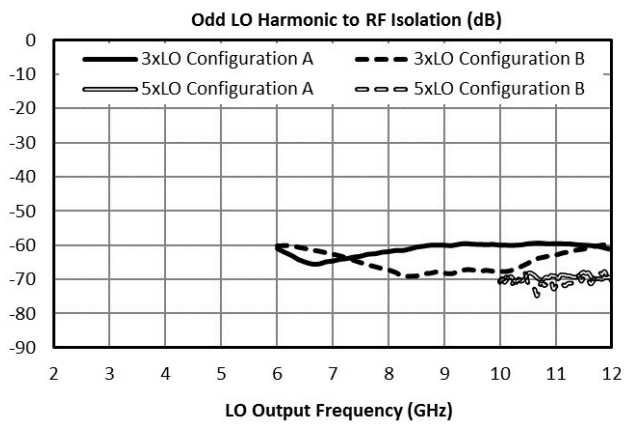
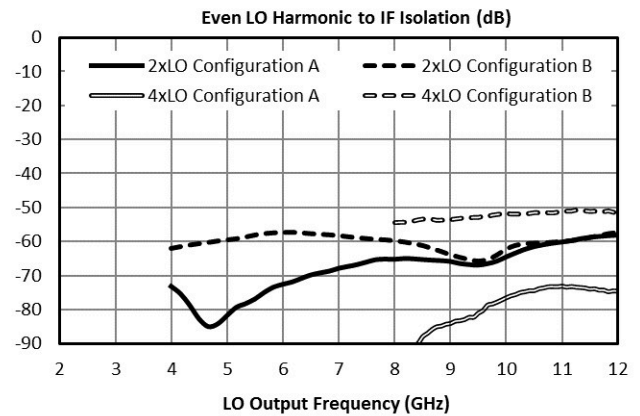
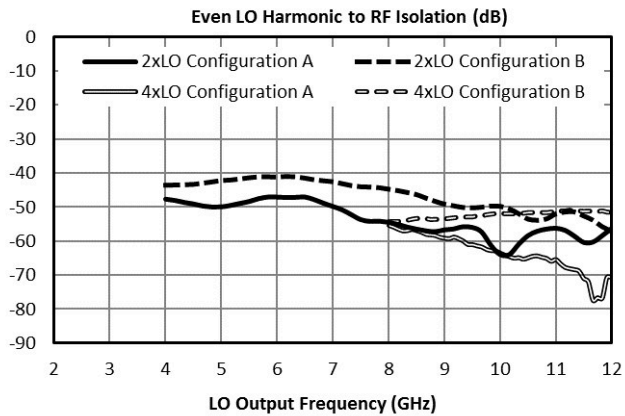




Typical Performance Plots: IP3



Typical Performance Plots: LO Harmonic Isolation



Spur Table

Typical Spurious Performance: Down-Conversion

Typical spurious data is provided by selecting RF and LO frequencies ($\pm m \cdot LO \pm n \cdot RF$) within the RF/LO bands, to create a spurious output within the IF band. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by (n-1), where "n" is the RF spur order. For example, the 2RF x 2LO spur is 81 dBc for a -10 dBm input, so a -20 dBm RF input creates a spur that is (2-1) x (-10 dB) lower, or 91 dBc. Data is shown for the frequency plan in 3.6 Typical Performance.

Typical Down-conversion spurious suppression (dBc): Config A (B)

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xRF	30 (15)	Reference	33 (32)	11 (13)	43 (40)	24 (27)
2xRF	72 (71)	56 (57)	81 (82)	68 (65)	70 (74)	73 (66)
3xRF	93 (84)	61 (62)	89 (94)	77 (77)	90 (92)	68 (71)
4xRF	125 (130)	104 (110)	114 (118)	115 (116)	126 (130)	113 (116)
5xRF	139 (149)	120 (122)	127 (132)	116 (121)	136 (143)	123 (129)

Typical Spurious Performance: Up-Conversion

Typical spurious data is taken by mixing an input within the IF band, with LO frequencies ($\pm m \cdot LO \pm n \cdot IF$), to create a spurious output within the RF output band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where “n” is the IF spur order. For example, the 2IFx1LO spur is typically 74 dBc for a -10 dBm input with a sine-wave LO, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) lower, or 84 dBc. Data is shown for the frequency plan in 3.6 Typical Performance.

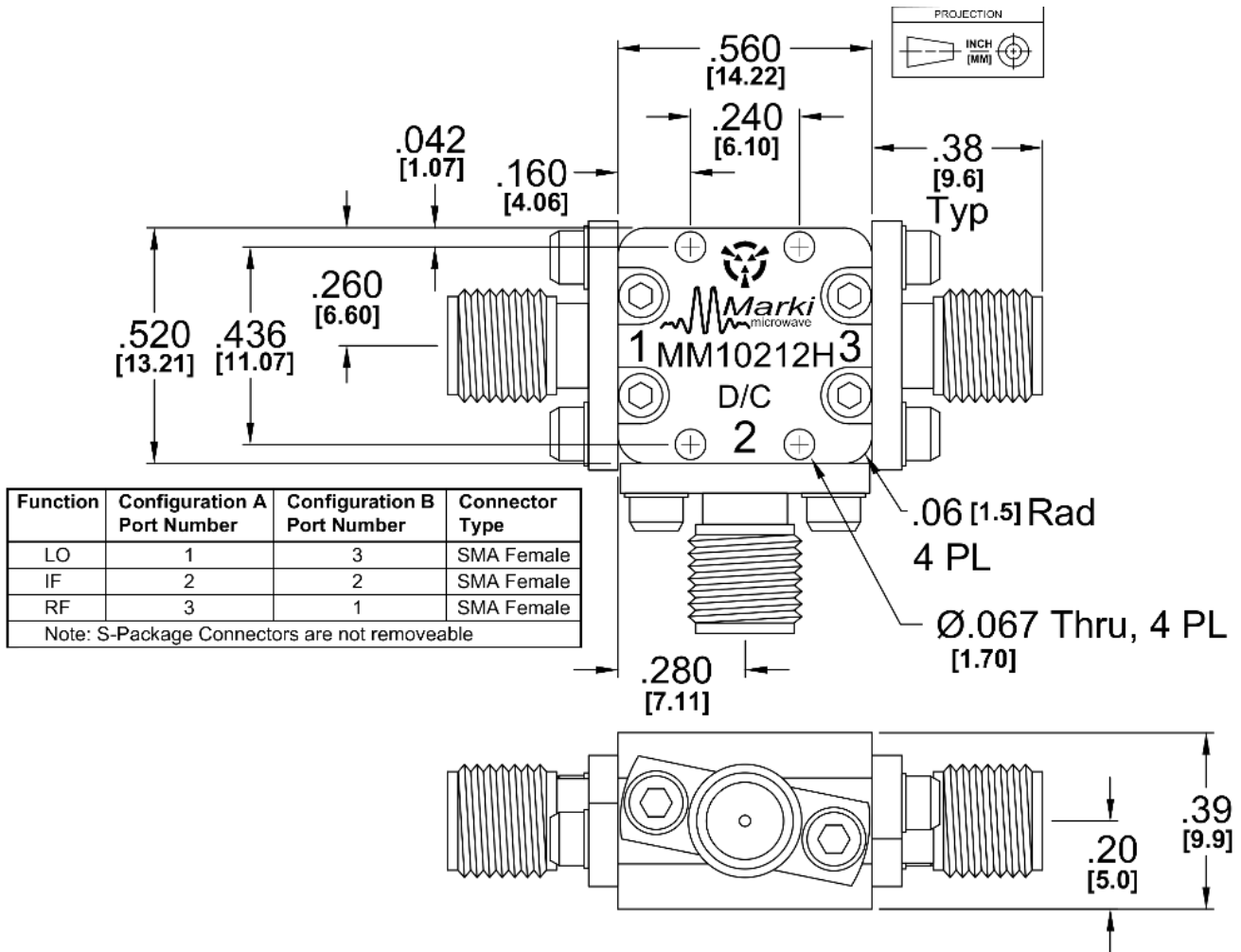
Typical Up-conversion spurious suppression (dBc): Config A (B)

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xIF	27 (19)	Reference	34 (34)	11 (12)	43 (38)	32 (25)
2xIF	55 (70)	74 (76)	59 (56)	79 (79)	65 (58)	79 (76)
3xIF	92 (83)	73 (71)	82 (83)	64 (66)	86 (87)	72 (70)
4xIF	119 (120)	125 (126)	115 (111)	120 (123)	109 (106)	120 (120)
5xIF	139 (139)	114 (114)	130 (132)	105 (107)	129 (125)	111 (105)

Mechanical Data

Outline Drawing

Download : [Outline 2D Drawing](#) | [Outline 3D Drawing](#) | [Outline 3D STP](#)



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